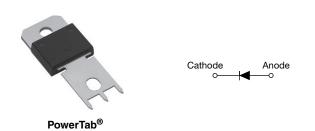
Vishay Semiconductors

Ultrafast Soft Recovery Diode, 80 A FRED Pt®



www.vishay.com

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	80 A			
V _R	200 V			
V _F at I _F	0.79 V			
t _{rr} (typ.)	See recovery table			
T _J max.	175 °C			
Package	PowerTab [®]			
Circuit configuration	Single			

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

MECHANICAL DATA

Case: PowerTab[®] Molding compound meets UL 94 V-0 flammability rating **Terminal:** nickel plated screwable

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V _R		200	V
Continuous forward current	I _{F(AV)}	T _C = 112 °C	80	
Single pulse forward current	I _{FSM}	T _C = 25 °C	800	А
Maximum repetitive forward current	I _{FRM}	Square wave, 20 kHz	160	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP.		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _r	I _R = 50 μA	200	-	-	N
Forward voltage	V	I _F = 80 A	-	0.94	1.13	V
Forward voltage V _F	I _F = 80 A, T _J = 175 °C	-	0.79	0.92		
Reverse leakage current	1	$V_{R} = V_{R}$ rated	-	-	50	μA
Reverse leakage current I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	2	mA	
Junction capacitance	CT	V _R = 200 V	-	89	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nH

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COMPLIANT

HALOGEN

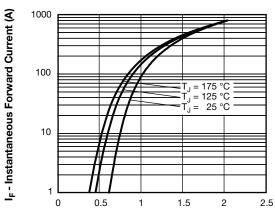
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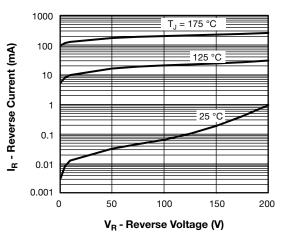
DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	-	35	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	32	-	ns
		T _J = 125 °C		-	52	-	
Peak recovery current I _{RRM}		T _J = 25 °C	I _F = 80 A V _B = 160 V	-	4.4	-	Α
	T _J = 125 °C	v _R = 160 v dl _F /dt = 200 A/µs	-	8.8	-	~	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	70	-	nC
		T _J = 125 °C		-	240	-	nc

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.70	°C/W
Thermal resistance, junction to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	0/10
Weight			-	-	5.02	g
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style PowerTab®		80E	3U02	

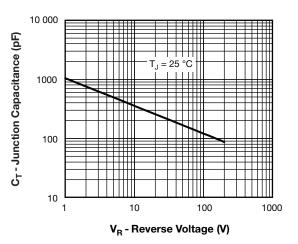


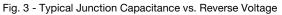
V_{FM} - Forward Voltage Drop (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics



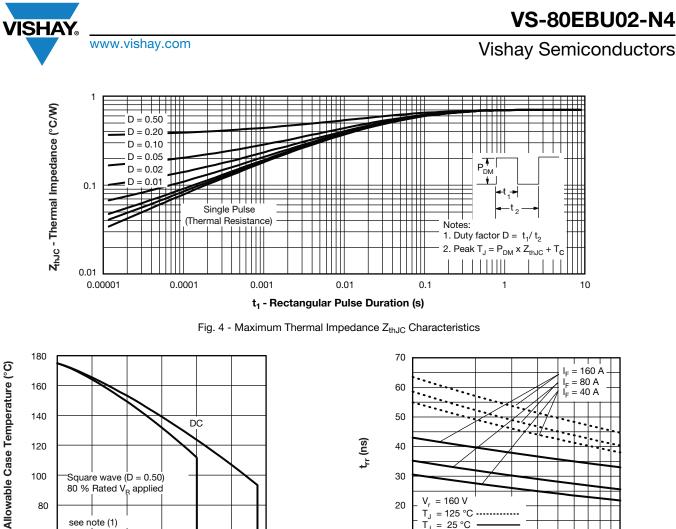






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t_{rr} (ns)

Q_{rr} (nC)

40

30

20

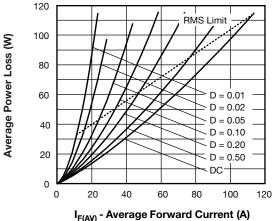
10 100

= 160 V ٧.

 $T_J = 25 °C$

= 125 °C

ТJ



Square wave (D = 0.50) 80 % Rated V_R applied

40

60

I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

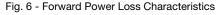
80

100

120

see note (1)

20



Note

120

100

80

60

0

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

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dl_F/dt (A/µs) Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt 1200 V, = 160 V = 125 °C T, 1000 = 25 °C Т, 800 $I_{F} = 160 \text{ A}^{-1}$ I_E = 80 A

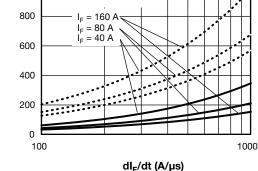


Fig. 8 - Typical Stored Charge vs. dl_F/dt

VS-80EBU02-N4

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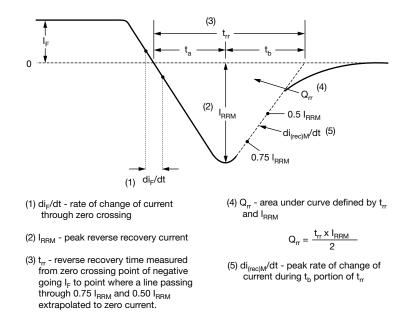
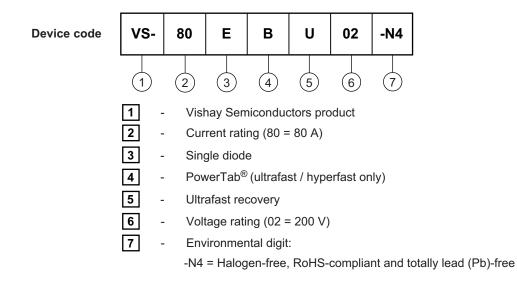


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)				
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-80EBU02-N4	25/tube	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			

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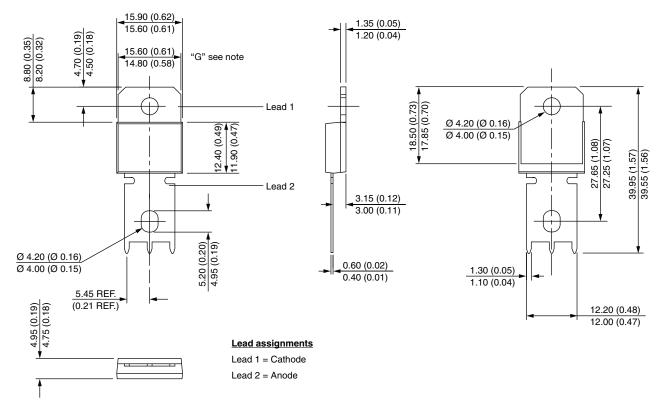
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PowerTab[®]

DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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